C3A Epithelium Cells Directly Cultured on High-Dielectric Constant Material for Light-Addressable Potentiometric Sensor †

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Abstract: To investigate the ion activities of cells based on light-addressable potentiometric sensor (LAPS) platform, various high-dielectric constant sensing membrane were investigated the visibility and potential issue. Three different kinds of well-proven materials in semiconductor industry, such as Si3N4, NbOx, and TiN, are the promising sensing membranes to directly culture C3A cells. TiN and NbOx could be the potential candidate. The photocurrent and flatband voltage difference generated by acidification reaction is verified to observe by LAPS is the future.

Keywords: C3A; chemical image; LAPS

1. Introduction

Light-addressable potentiometric sensor (LAPS) was proposed as the platform to obtain the 2D images of cells [1]. Some cells were proven to be cultured on sensing membrane of LAPS, which may need an optimization in the culture process since the material properties changes from glass dish [2,3]. However some issues including apoptosis in culture could be found in the measurement procedure. In this study, 3 different high-dielectric constant materials were fabricated on LAPS device to verify the possibility of cell culture.

2. Materials and Methods

The process flow and schematic plot of sensor structure were shown in Figure 1. The P-type Si wafer was used as semiconductor of LAPS. For LAPS with Si3N4 and TiN sensing membrane, a buffer layer of thermally-grown SiO2 was fabricated firstly. Both Si3N4 [4] and TiN [5] were proven as a good sensing membrane in field-effect sensors. However NbOx layer was directly deposited on Si surface [5,6]. Then an encapsulation with a polydimethyl-siloxane (PDMS) tank with a design of 2layer
structure was attached to high-dielectric constant layer as the container for cell culture. The bottom layer with 4 small wells and the top layer with 1 big well are used for LAPS measurement and cell culture, respectively. An epithelium cell line of human liver cancer, HepG2/C3A, is cultured directly on LAPS within the area of 4 wells. Culture medium MEM contains 10% fetal bovine serum was used for maintenance. Culture medium was refreshed every 2 days and then subculture once a week then incubated in 37 °C and 5% CO₂. After cultured, the response of C3A cells could be measured by the photocurrent versus bias voltage curves of LAPS system [6].

![Figure 1. (a) Schematic plot of 3 device structures and (b) its process flow.](image)

### 3. Results & Discussion

First of all, seeding different number of C3A cells on each sample for 24 to 48 h. After cultured in the same incubator, optical microscope (OM) pictures with C3A cells cultured on different surface is shown in Figure 2a–d. It can be clearly seen C3A cells could be cultured well on glass dish. The health status of C3A cells on high-dielectric constant could be in the rank as TiN > NbOx > Si₃N₄ layer. It could be a good reference of surface status to the photovoltage versus bias voltage curves. As shown in Figure 3a, photocurrent versus bias voltage curves of 3 different sensors could be clearly observed. With thinner insulator layer, higher photovoltage could be found. The shift between standard buffer solution of pH 2 and 12 could be used to calculated the pH sensitivity. The largest shift could be found in NbOx, which is matched to expectations. Cell acidification for 30 min from the medium changes to HBSS will make the photovoltage versus bias voltage curves shift negative bias in the Si₃N₄/SiO₂ LAPS as shown in Figure 3b. With the lower pH value of sensing membrane surface, the photovoltage versus bias voltage will be shifted to negative bias based on the mechanism of LAPS operation. Current data shows Si₃N₄ membrane is acceptable for cell culture. Other material should be investigated to match cell properties in culture process. This proposed methodology could be further investigated to get 2D images of cell status and the following toxicity and drug test.
4. Conclusions

Firstly, 3 different high-dielectric constant materials of LAPS are applied as the surface of cell culture. Direct cell culture on these membranes shows big differences on the optical microscope images. In the meantime, photovoltage versus bias voltage measured by LAPS system could be used to monitor the cell acidification with a negative shift in bias voltage after 30 min. This platform could be a potential tool to evaluate the cell status and relatively drug effects.

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References


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